RS1AD THRU RS1MD

Surface Mount Fast Recovery Rectifiers Reverse Voltage - 50 to 1000 V Forward Current - 1 A

Features

- · High current capability
- · High surge current capability
- High reliability
- · Low reverse current
- · Fast switching for high efficiency

Mechanical Data

• Case: SMA (DO-214AC) molded plastic

• Mounting position: Any

• Lead: Lead formed for surface mount

• Polarity: Color band denotes cathode end

SMA (DO-214AC) 0.087(2.21) 0.039(1.0) 0.183(4.65) 0.157(3.99) 0.012(0.305) 0.005(0.13) 0.060(1.52) 0.030(0.76) 0.023(5.66) 0.185(4.70) 0.008(0.203)Max.

Dimensions in inches and (millimeters)

Absolute Maximum Ratings and Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

1 or capacitive load, delate current by 2070.									
Parameter	Symbols	RS1AD	RS1BD	RS1DD	RS1GD	RS1JD	RS1KD	RS1MD	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Current at T _L = 90 °C	I _{F(AV)}	1							Α
Peak Forward Surge Current 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	30							А
Maximum Forward Voltage at 1 A	V _F	1.3							V
Maximum DC Reverse Current at T _A = 25°C	I _R	5							μΑ
at Rated DC Blocking Voltage at $T_A = 100$ °C		50							
Maximum Reverse Recovery Time 1)	t _{rr}		1	50		250	50	00	ns
Typical Junction Capacitance 2)	CJ	15							pF
Typical Thermal Resistance 3)	R _{θJA}	50							°C/W
Operating and Storage Temperature Range	T_{j} , T_{stg}	- 65 to + 150							°C

 $^{^{1)}}$ Reverse recovery test conditions I_F = 0.5 A, I_R = 1 A, I_{rr} = 0.25 A.



 $^{^{\}rm 2)}\mbox{Measured}$ at 1 MHz and applied reverse voltage of 4 V.

 $^{^{3)}\}mbox{P.C.B.}$ mounted with 0.2 X 0.2″(5 X 5 mm) copper pad areas.

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